## NSN 5961-00-577-0390

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View Online at https://aerobasegroup.com/nsn/5961-00-577-0390 **Inclosure Material:** Metal **Overall Length:** 0.300 inches **Overall Diameter:** 0.550 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 collector to base voltage/static/emitter open and 100.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, instantaneous **Current Rating Per Characteristic:** 30.00 amperes source cutoff current and 7.50 amperes source cutoff current **Power Rating Per Characteristic:** 200.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: pnp **Precious Material And Location:** Leads gold **Precious Material:** Gold **Terminal Type And Quantity:** 1 case and 2 pin Shelf Life:

No

N/a

**Unit Of Measure:** 

Demilitarization:

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